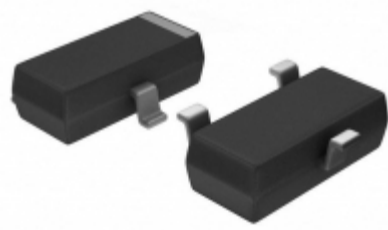
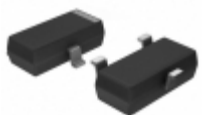


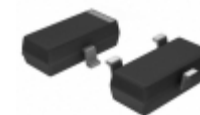




	<h2 style="color: red;">FJV4106RMTF</h2>
	<p>Hersteller-Teilenummer: FJV4106RMTF</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: TRANS PREBIAS PNP 200MW SOT23-3</p> <p>Datenblätter: 1.FJV4106RMTF.pdf 2.FJV4106RMTF.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 107450 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FJV4106RMTF
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS PREBIAS PNP 200MW SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	107450 pcs Stock
detaillierte Beschreibung	Pre-Biased Bipolar Transistor (BJT) PNP - Pre-Biased
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Transistor-Typ	PNP - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 500µA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	68 @ 5mA, 5V
Frequenz - Übergang	200MHz
Verpackung	Tape & Reel (TR)
Widerstand - Basis (R1)	10 kOhms
Widerstand - Emitterbasis (R2)	47 kOhms
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

FJV4106RMTF ist neu im Original, Suche FJV4106RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV4106RMTF AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV4106RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

 FJV4108RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3	 FJV4104RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3	 FJV4106RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3	 FJV4103RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3
 FJV4105RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3	 FJV4107RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3	 FJV4108RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3	 FJV4107RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3

heiße Teile

Mehr

⊗ FJV3108RMTF	↔ FJV3108RMTF	⇒ FJV3109R	D FJV3109RMTF	⇒ FJV3109RMTF
⊣ FJV3110RMTF	⊗ FJV3110RMTF	D FJV3111RMTF	⇒ FJV3111RMTF	⇒ FJV3112RMTF
⊗ FJV3112RMTF	⊣ FJV3113RMTF	⊗ FJV3113RMTF	↔ FJV3114RMTF	⇒ FJV3114RMTF
D FJV3115RMTF	⊗ FJV3115RMTF	⊣ FJV4101RMTF	⊗ FJV4101RMTF	⇒ FJV4102RLIMTF
⇒ FJV4102RMTF	↔ FJV4102RMTF	⊗ FJV4103RMTF	⊣ FJV4103RMTF	⇒ FJV4104RMTF
↔ FJV4104RMTF	⇒ FJV4105RMTF	D FJV4105RMTF	⊗ FJV4106RMTF	⊣ FJV4107RMTF
⊗ FJV4107RMTF	D FJV4108RMTF	⇒ FJV4108RMTF	↔ FJV4109RMTF	⇒ FJV4109RMTF
⊣ FJV4110RMTF	⊗ FJV4110RMTF	↔ FJV4111RMTF	⇒ FJV4111RMTF	⇒ FJV4112RMTF
⊗ FJV4112RMTF	⊣ FJV4113RMTF	⊗ FJV4113RMTF	D FJV4114RMTF	⇒ FJV4114RMTF
↔ FJV42MTF	⊗ FJV42MTF	⊣ FJV992EMTF	⊗ FJV992PMTF	⇒ FJV992PMTF

Contact us: Info@Y-IC.com

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